	Туре	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	1234	capacitor and (HSG or (Hemispherical adj grain))	USPAT; EPO; JPO; DERWEN T; IBM	
2	BRS	L2	107277 9		USPAT; EPO; JPO; DERWEN T; IBM TDB	
3	BRS	L3	1059	1 and 2	USPAT; EPO; JPO; DERWEN T; IBM TDB	
4	BRS	L4	790	<pre>3 and ((polysilicon or polycrystal\$) and (open\$ or window or hole or via or trench))</pre>	USPAT; EPO; JPO; DERWEN T; IBM TDB	09:17
5	BRS	L7	768	dielectrice or rugg\$ or polysilicon or undop\$ orseed or chemisorb\$ or	EPO;	
6	BRS	L9	66	"5142438"	USPAT; EPO; JPO; DERWEN T; IBM TDB	

	Туре	L #	Hits	Search Text	DBs	Time Stamp
7	BRS	L10	27	"5362632"	USPAT; EPO; JPO; DERWEN T; IBM TDB	
8	BRS	L8	601	7 and (TaO or ZrO or WO or AlO or HfO or monolayer or side or bottom)	USPAT; EPO; JPO; DERWEN T; IBM TDB	10:05